



Taiwan Semiconductor

# PerF≝T<sup>™</sup>Power Transistor

### **FEATURES**

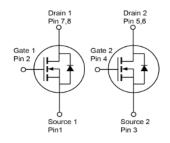
- Ultra-low On-resistance
- Wettable Flank leads for Enhanced AOI
- 100% UIS and Rg tested
- 175°C Operating Junction Temperature
- **RoHS Compliant**
- Halogen-Free according to IEC 61249-2-21

PRODUCT SUMMARY				
PARAMETER		VALUE	UNIT	
$V_{DS}$		40	V	
R <sub>DS(on)</sub> (max)	$V_{GS} = 10V$	7.6		
	$V_{GS} = 4.5V$	10.6	mΩ	
$Q_{g}$	$V_{GS} = 4.5V$	10.7	nC	

#### **APPLICATIONS**

- DC-DC Converters
- Solenoid and Motor Drivers
- Load Switch





Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>A</sub> = 25°C unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		$V_{DS}$	40	V
Gate-Source Voltage		$V_{GS}$	±16	V
Continuous Drain Current, Silicon limited	$T_C = 25^{\circ}C$	$I_D$	65	Α
	$T_C = 25^{\circ}C$		34	
Continuous Drain Current (Note 1)	$T_C = 100$ °C	I <sub>D</sub>	34	Α
	$T_A = 25$ °C		15	
Pulsed Drain Current		I <sub>DM</sub>	136	А
Single Pulse Avalanche Current (Note 2)		I <sub>AS</sub>	17.3	А
Single Pulse Avalanche Energy (Note 2)		E <sub>AS</sub>	45	mJ
Total Bower Dissipation	T <sub>C</sub> = 25°C	D	55.6	W
Total Power Dissipation	$T_C = 125$ °C	$P_D$	18.5	VV
Operating Junction and Storage Temperature Range		$T_J,T_STG$	-55 to +175	°C

THERMAL RESISTANCE				
PARAMETER	SYMBOL	MAXIMUM	UNIT	
Thermal Resistance – Junction to Case	R <sub>OJC</sub>	2.7	°C/W	
Thermal Resistance – Junction to Ambient	$R_{\Theta JA}$	50	°C/W	

Note: ReJA is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.

1



ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static					•	
Drain-Source Breakdown Voltage	$V_{GS} = 0V$ , $I_D = 1mA$	BV <sub>DSS</sub>	40			V
Gate Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	$V_{GS(TH)}$	1.4	1.8	2.2	V
Gate-Source Leakage Current	$V_{GS} = \pm 16V, V_{DS} = 0V$	I <sub>GSS</sub>			±100	nA
Drain-Source Leakage Current	$V_{GS} = 0V, V_{DS} = 40V$	I <sub>DSS</sub>			1	μA
	$V_{GS} = 0V, V_{DS} = 40V$ $T_{J} = 125^{\circ}C$				100	
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 17A$			6.1	7.6	mΩ
(Note 3)	$V_{GS} = 4.5V, I_D = 17A$	R <sub>DS(on)</sub>		7.7	10.6	
Forward Transconductance (Note 3)	$V_{DS} = 10V, I_{D} = 10A$	g <sub>fs</sub>		133.3		S
Dynamic						
Total Gate Charge	$V_{GS} = 4.5V, V_{DS} = 20V,$ $I_{D} = 15A$	$Q_g$		10.7		
Total Gate Charge	V <sub>GS</sub> = 10V, V <sub>DS</sub> = 20V,	$Q_g$		22.4		nC
Gate-Source Charge		$Q_{gs}$		4.3		
Gate-Drain Charge	I <sub>D</sub> = 15A	$Q_{gd}$		3.3		
Input Capacitance	01/ 1/ 051/	C <sub>iss</sub>		1344		
Output Capacitance	$V_{GS} = 0V, V_{DS} = 25V,$ f = 1.0MHz	C <sub>oss</sub>		248		pF
Reverse Transfer Capacitance	1 = 1.0W112	C <sub>rss</sub>		15		
Gate Resistance	f = 1.0MHz	$R_g$		1.7		Ω
Switching (Note 4)						
Turn-On Delay Time		t <sub>d(on)</sub>		7.3		
Rise Time	$V_{GS} = 10V, V_{DS} = 20V,$ $I_{D} = 15A, R_{G} = 3.3\Omega$	t <sub>r</sub>		50.1		
Turn-Off Delay Time		t <sub>d(off)</sub>		23.6		nS
Fall Time		t <sub>f</sub>		5.6		
Source-Drain Diode						
Diode Forward Voltage (Note 3)	$V_{GS} = 0V, I_{S} = 17A$	$V_{SD}$			1.1	V
Reverse Recovery Time	I <sub>S</sub> = 15A,	t <sub>rr</sub>		29.4		nS
Reverse Recovery Charge	di/dt = 100A/µs	$Q_{rr}$		20		nC

# Notes:

- 1. Package current limit.
- 2. L = 0.3 mH,  $V_{GS} = 10 V$ ,  $R_G = 25 \Omega$ , Starting  $T_J = 25 ^{\circ} C$ .
- 3. Pulse test: Pulse Width  $\leq$  300µs, duty cycle  $\leq$  2%.
- 4. Switching time is essentially independent of operating temperature.

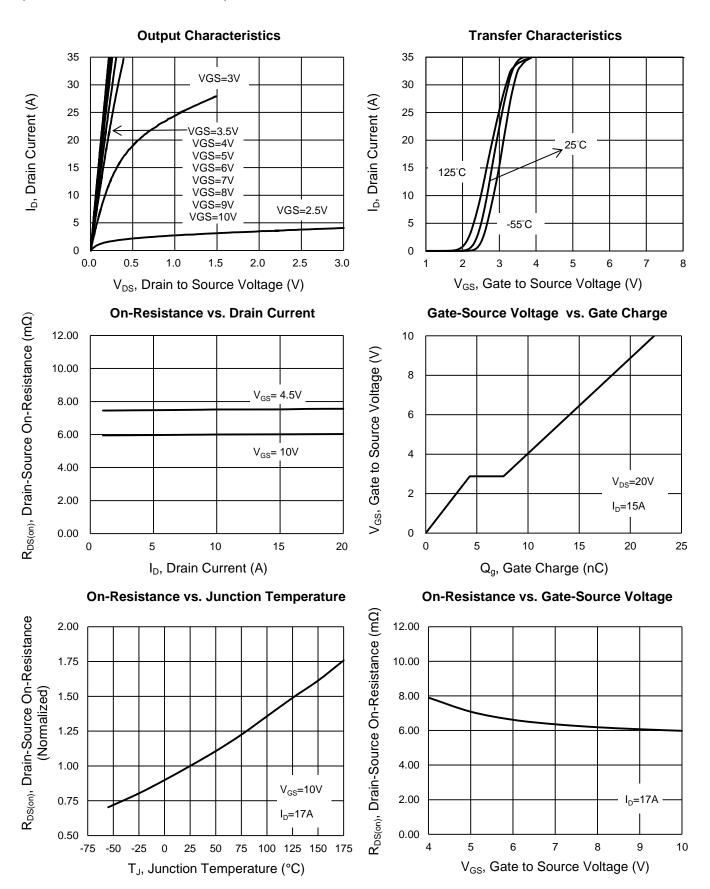
# **ORDERING INFORMATION**

ORDERING CODE	PACKAGE	PACKING
TSM076NH04LDCR RLG	PDFN56U Dual	2,500pcs / 13" Reel



#### **CHARACTERISTICS CURVES**

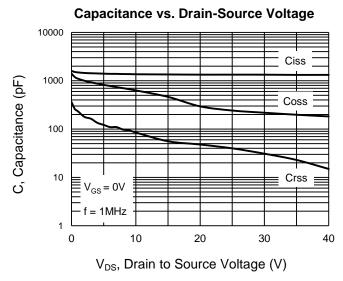
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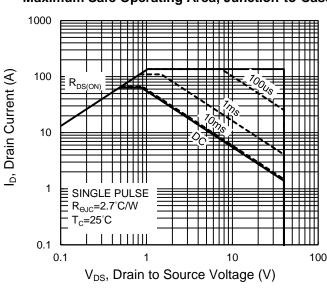
#### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 



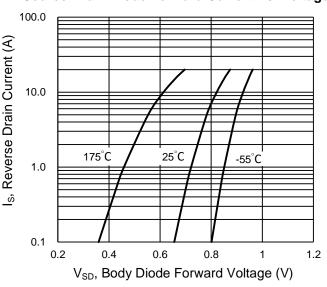
BV<sub>DSS</sub> vs. Junction Temperature 1.20 Drain-Source Breakdown Voltage 1.15 BV<sub>DSS</sub> (Normalized) 1.10 1.05 1.00 0.95 0.90 0.85  $I_D=1mA$ 0.80 75 100 125 150 175 -75 -50 -25 25 50

#### Maximum Safe Operating Area, Junction-to-Case

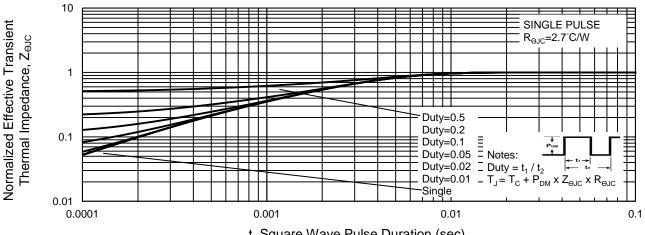


# Source-Drain Diode Forward Current vs. Voltage

T<sub>J</sub>, Junction Temperature (°C)



#### Normalized Thermal Transient Impedance, Junction-to-Case

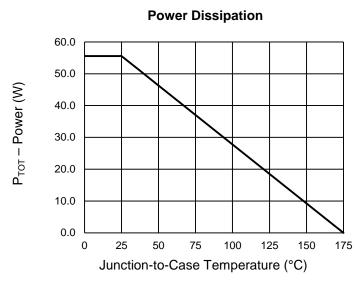


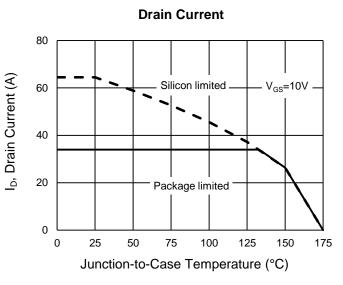
t, Square Wave Pulse Duration (sec)



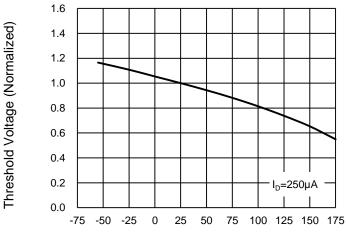
# **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)





# Normalized gate threshold voltage vs Temperature



T<sub>J</sub>, Junction Temperature (°C)

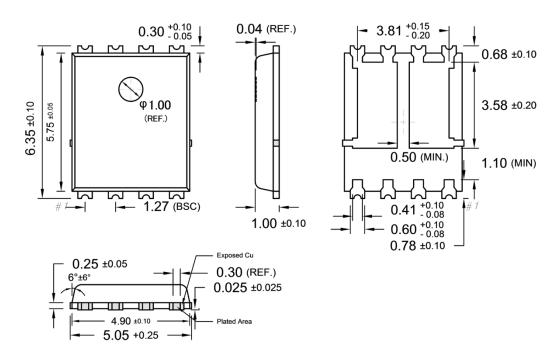
Version: D2207

5

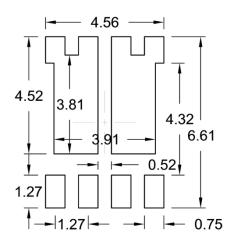


# PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

#### PDFN56U Dual



# SUGGESTED PAD LAYOUT (Unit: Millimeters)



#### **MARKING DIAGRAM**



Y = Year Code

**WW** = Week Code (01~52)

 $\mathbf{L} = \text{Lot Code } (1~9,A~Z)$ 

**F** = Factory Code



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